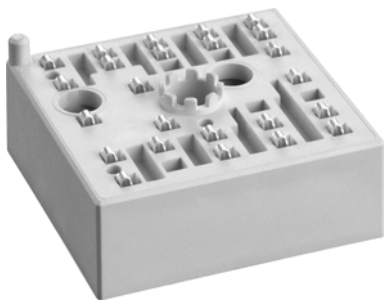


SKiiP 11NAB12T4V1



MiniSKiiP® 1

SKiiP 11NAB12T4V1

Features

- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

Typical Applications*

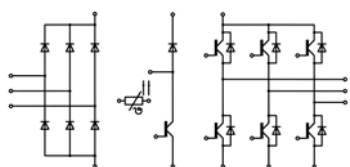
- Inverter up to 8 kVA
- Typical motor power 4 kW

Remarks

- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +150^\circ\text{C}$)
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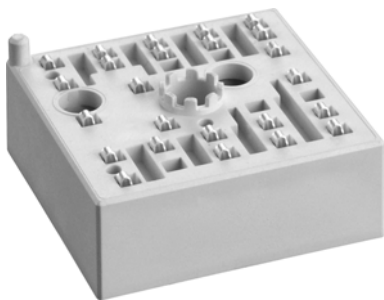
Absolute Maximum Ratings

Symbol	Conditions	Values	Unit
Inverter - IGBT			
V_{CES}	$T_j = 25^\circ\text{C}$	1200	V
I_C	$\lambda_{paste}=0.8 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	18
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	15
I_C	$\lambda_{paste}=2.5 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	19
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	16
I_{Cnom}		8	A
I_{CRM}	$I_{CRM} = 3 \times I_{Cnom}$	24	A
V_{GES}		-20 ... 20	V
t_{psc}	$V_{CC} = 800 \text{ V}$	$T_j = 150^\circ\text{C}$	10
	$V_{GE} \leq 15 \text{ V}$		
	$V_{CES} \leq 1200 \text{ V}$		
T_j		-40 ... 175	$^\circ\text{C}$
Chopper - IGBT			
V_{CES}	$T_j = 25^\circ\text{C}$	1200	V
I_C	$\lambda_{paste}=0.8 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	18
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	15
I_C	$\lambda_{paste}=2.5 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	19
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	16
I_{Cnom}		8	A
I_{CRM}	$I_{CRM} = 3 \times I_{Cnom}$	24	A
V_{GES}		-20 ... 20	V
t_{psc}	$V_{CC} = 800 \text{ V}$	$T_j = 150^\circ\text{C}$	10
	$V_{GE} \leq 15 \text{ V}$		
	$V_{CES} \leq 1200 \text{ V}$		
T_j		-40 ... 175	$^\circ\text{C}$
Inverse - Diode			
V_{RRM}	$T_j = 25^\circ\text{C}$	1200	V
I_F	$\lambda_{paste}=0.8 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	15
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	12
I_F	$\lambda_{paste}=2.5 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	17
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	13
I_{Fnom}		8	A
I_{FRM}	$I_{FRM} = 3 \times I_{Fnom}$	24	A
I_{FSM}	$t_p = 10 \text{ ms, sin } 180^\circ, T_j = 150^\circ\text{C}$	36	A
T_j		-40 ... 175	$^\circ\text{C}$
Freewheeling - Diode			
V_{RRM}	$T_j = 25^\circ\text{C}$	1200	V
I_F	$\lambda_{paste}=0.8 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	15
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	12
I_F	$\lambda_{paste}=2.5 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	17
	$T_j = 175^\circ\text{C}$	$T_s = 70^\circ\text{C}$	13
I_{Fnom}		8	A
I_{FRM}	$I_{FRM} = 3 \times I_{Fnom}$	24	A
I_{FSM}	$t_p = 10 \text{ ms, sin } 180^\circ, T_j = 150^\circ\text{C}$	36	A
T_j		-40 ... 175	$^\circ\text{C}$



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SKiiP 11NAB12T4V1



MiniSKiiP® 1

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Typical Applications*

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- Typical motor power 4 kW

Remarks

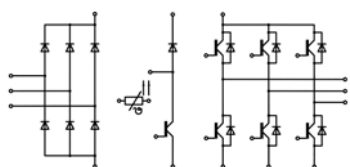
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- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information

Absolute Maximum Ratings

Symbol	Conditions	Values	Unit	
Rectifier - Diode				
V_{RRM}	$T_j = 25^\circ\text{C}$	1600	V	
I_F	$\lambda_{paste}=0.8 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	39	A
	$T_j = 150^\circ\text{C}$	$T_s = 70^\circ\text{C}$	29	A
I_F	$\lambda_{paste}=2.5 \text{ W/(mK)}$	$T_s = 25^\circ\text{C}$	42	A
	$T_j = 150^\circ\text{C}$	$T_s = 70^\circ\text{C}$	32	A
I_{Fnom}		8	A	
I_{FSM}	10 ms	$T_j = 25^\circ\text{C}$	220	A
	sin 180°	$T_j = 150^\circ\text{C}$	200	A
I^2t	10 ms	$T_j = 25^\circ\text{C}$	242	A ² s
	sin 180°	$T_j = 150^\circ\text{C}$	200	A ² s
T_j		-40 ... 150	°C	
Module				
$I_{t(RMS)}$	$T_{terminal} = 80^\circ\text{C}$,	12	A	
T_{stg}		-40 ... 125	°C	
V_{isol}	AC sinus 50 Hz, 1 min	2500	V	

Characteristics

Symbol	Conditions	min.	typ.	max.	Unit
Inverter - IGBT					
$V_{CE(sat)}$	$I_C = 8 \text{ A}$ $V_{GE} = 15 \text{ V}$ chiplevel	$T_j = 25^\circ\text{C}$	1.85	2.10	V
		$T_j = 150^\circ\text{C}$	2.25	2.45	V
V_{CE0}	chiplevel	$T_j = 25^\circ\text{C}$	0.80	0.90	V
		$T_j = 150^\circ\text{C}$	0.70	0.80	V
r_{CE}	$V_{GE} = 15 \text{ V}$ chiplevel	$T_j = 25^\circ\text{C}$	131	150	mΩ
		$T_j = 150^\circ\text{C}$	194	206	mΩ
$V_{GE(th)}$	$V_{GE} = V_{CE} \text{ V}, I_C = 1 \text{ mA}$	5	5.8	6.5	V
I_{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 1200 \text{ V}, T_j = 25^\circ\text{C}$		0.1	0.3	mA
C_{ies}	$V_{CE} = 25 \text{ V}$ $V_{GE} = 0 \text{ V}$	$f = 1 \text{ MHz}$	0.49		nF
C_{oes}		$f = 1 \text{ MHz}$	0.05		nF
C_{res}		$f = 1 \text{ MHz}$	0.03		nF
Q_G	$V_{GE} = -8 \text{ V} \dots +15 \text{ V}$		45		nC
R_{Gint}	$T_j = 25^\circ\text{C}$		0		Ω
$t_{d(on)}$	$V_{CC} = 600 \text{ V}$ $I_C = 8 \text{ A}$	$T_j = 150^\circ\text{C}$	31		ns
t_r		$T_j = 150^\circ\text{C}$	31		ns
E_{on}	$R_{Gon} = 47 \Omega$ $R_{Goff} = 47 \Omega$	$T_j = 150^\circ\text{C}$	0.87		mJ
$t_{d(off)}$		$T_j = 150^\circ\text{C}$	290		ns
t_f		$T_j = 150^\circ\text{C}$	70		ns
E_{off}	$V_{GE} = +15/-15 \text{ V}$	$T_j = 150^\circ\text{C}$	0.74		mJ
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=0.8 \text{ W/(mK)}$		1.84		K/W
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=2.5 \text{ W/(mK)}$		1.58		K/W



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SKiiP 11NAB12T4V1



MiniSKiiP® 1

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- Highly reliable spring contacts for electrical connections
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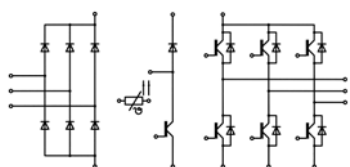
Typical Applications*

- Inverter up to 8 kVA
- Typical motor power 4 kW

Remarks

- Max. case temperature limited to $T_C=125^\circ\text{C}$
- Product reliability results valid for $T_j \leq 150^\circ\text{C}$ (recommended $T_{j,op} = -40 \dots +150^\circ\text{C}$)
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Chopper - IGBT						
$V_{CE(sat)}$	$I_C = 8 \text{ A}$ $V_{GE} = 15 \text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$		1.85	2.10	V
		$T_j = 150^\circ\text{C}$		2.25	2.45	V
V_{CE0}	chipelevel	$T_j = 25^\circ\text{C}$		0.80	0.90	V
		$T_j = 150^\circ\text{C}$		0.70	0.80	V
r_{CE}	$V_{GE} = 15 \text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$		131	150	m Ω
		$T_j = 150^\circ\text{C}$		194	206	m Ω
$V_{GE(th)}$	$V_{GE} = V_{CE} \text{ V}, I_C = 1 \text{ mA}$		5	5.8	6.5	V
I_{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 1200 \text{ V}, T_j = 25^\circ\text{C}$			0.1	0.3	mA
Q_G	$V_{GE} = -8 \text{ V} \dots +15 \text{ V}$			45		nC
R_{Gint}	$T_j = 25^\circ\text{C}$			0		Ω
$t_{d(on)}$	$V_{CC} = 600 \text{ V}$ $I_C = 8 \text{ A}$	$T_j = 150^\circ\text{C}$		31		ns
t_r	$R_{G on} = 47 \Omega$ $R_{G off} = 47 \Omega$	$T_j = 150^\circ\text{C}$		31		ns
E_{on}		$T_j = 150^\circ\text{C}$		0.87		mJ
$t_{d(off)}$		$T_j = 150^\circ\text{C}$		290		ns
t_f		$T_j = 150^\circ\text{C}$		70		ns
E_{off}	$V_{GE} = +15/-15 \text{ V}$	$T_j = 150^\circ\text{C}$		0.74		mJ
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=0.8 \text{ W}/(\text{mK})$			1.84		K/W
$R_{th(j-s)}$	per IGBT, $\lambda_{paste}=2.5 \text{ W}/(\text{mK})$			1.58		K/W
Inverse - Diode						
$V_F = V_{EC}$	$I_F = 8 \text{ A}$ $V_{GE} = 0 \text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$		2.33	2.65	V
		$T_j = 150^\circ\text{C}$		2.35	2.68	V
V_{F0}	chipelevel	$T_j = 25^\circ\text{C}$		1.30	1.50	V
		$T_j = 150^\circ\text{C}$		0.90	1.10	V
r_F	chipelevel	$T_j = 25^\circ\text{C}$		129	144	m Ω
		$T_j = 150^\circ\text{C}$		181	198	m Ω
I_{RRM}	$I_F = 8 \text{ A}$	$T_j = 150^\circ\text{C}$		8.3		A
Q_{rr}	$di/dt_{off} = 380 \text{ A}/\mu\text{s}$ $V_{GE} = -15 \text{ V}$	$T_j = 150^\circ\text{C}$		1.35		μC
E_{rr}	$V_{CC} = 600 \text{ V}$	$T_j = 150^\circ\text{C}$		0.57		mJ
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=0.8 \text{ W}/(\text{mK})$			2.53		K/W
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=2.5 \text{ W}/(\text{mK})$			2.2		K/W
Freewheeling - Diode						
$V_F = V_{EC}$	$I_F = 8 \text{ A}$ $V_{GE} = 0 \text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$		2.33	2.65	V
		$T_j = 150^\circ\text{C}$		2.35	2.68	V
V_{F0}	chipelevel	$T_j = 25^\circ\text{C}$		1.30	1.50	V
		$T_j = 150^\circ\text{C}$		0.90	1.10	V
r_F	chipelevel	$T_j = 25^\circ\text{C}$		129	144	m Ω
		$T_j = 150^\circ\text{C}$		181	198	m Ω
I_{RRM}	$I_F = 8 \text{ A}$	$T_j = 150^\circ\text{C}$		8.3		A
Q_{rr}	$di/dt_{off} = 380 \text{ A}/\mu\text{s}$ $V_{GE} = -15 \text{ V}$	$T_j = 150^\circ\text{C}$		1.35		μC
E_{rr}	$V_{CC} = 600 \text{ V}$	$T_j = 150^\circ\text{C}$		0.57		mJ
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=0.8 \text{ W}/(\text{mK})$			2.53		K/W
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=2.5 \text{ W}/(\text{mK})$			2.2		K/W



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SKiiP 11NAB12T4V1



MiniSKiiP® 1

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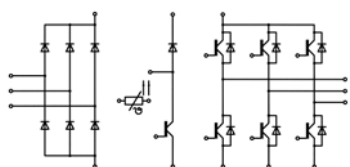
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- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
Rectifier - Diode						
$V_F = V_{EC}$	$I_F = 8 \text{ A}$ $V_{GE} = 0 \text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$		1.00	1.21	V
		$T_j = 125^\circ\text{C}$		0.90	1.10	V
V_{F0}	chipelevel	$T_j = 25^\circ\text{C}$		0.88	0.98	V
		$T_j = 125^\circ\text{C}$		0.73	0.83	V
r_F	chipelevel	$T_j = 25^\circ\text{C}$		15	29	m Ω
		$T_j = 125^\circ\text{C}$		21	34	m Ω
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=0.8 \text{ W/(mK)}$			1.5		K/W
$R_{th(j-s)}$	per Diode, $\lambda_{paste}=2.5 \text{ W/(mK)}$			1.29		K/W
Module						
M_s	to heat sink		2		2.5	Nm
w				30		g
L_{CE}				-		nH
Temperature Sensor						
R_{100}	$T_r = 100^\circ\text{C}$			1670 \pm 3%		Ω
$R(T)$	$R(T)=1000\Omega[1+A(T-25^\circ\text{C})+B(T-25^\circ\text{C})^2]$], $A = 7.635 \cdot 10^{-3} \text{ }^\circ\text{C}^{-1}$, $B = 1.731 \cdot 10^{-5} \text{ }^\circ\text{C}^{-2}$					



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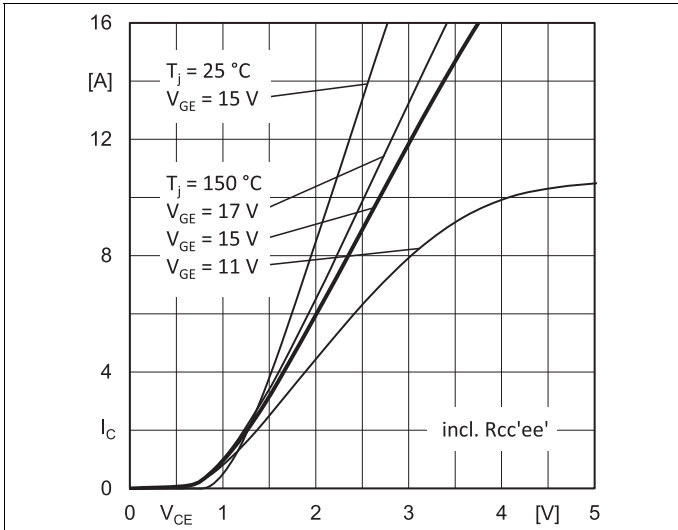


Fig. 1: Typ. output characteristic

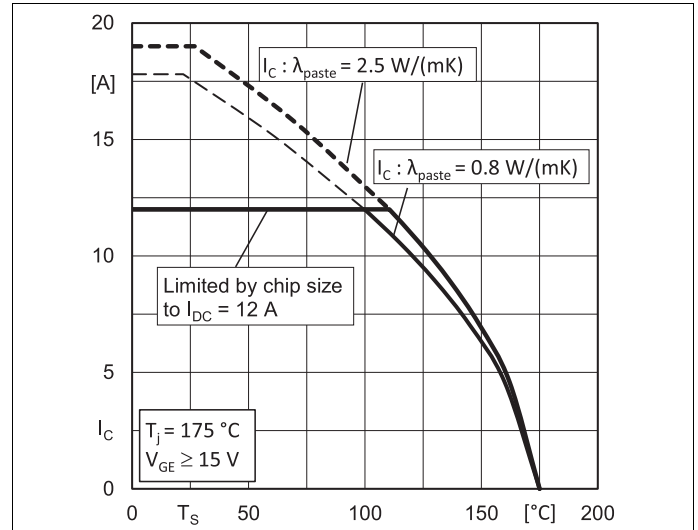


Fig. 2: Typ. rated current vs. temperature $I_C = f(T_s)$

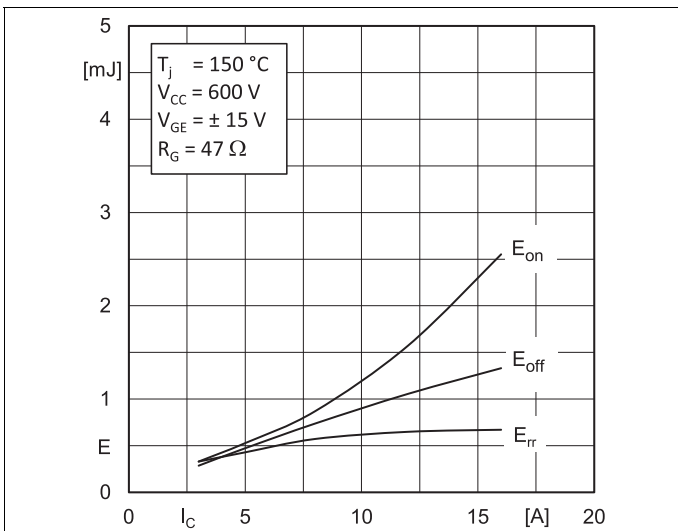


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

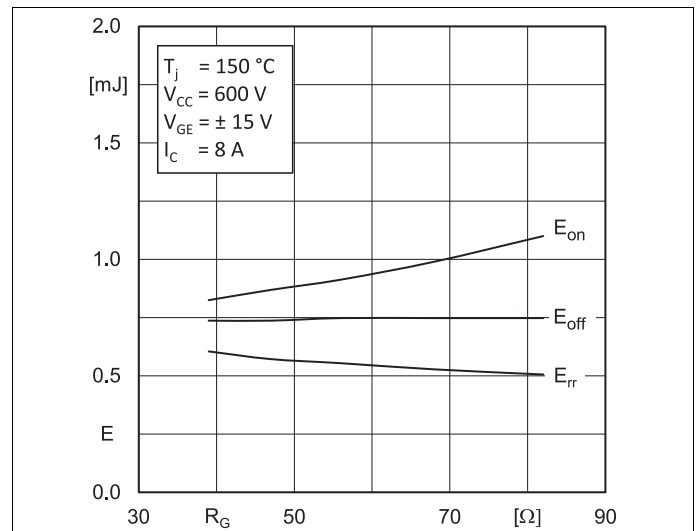


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

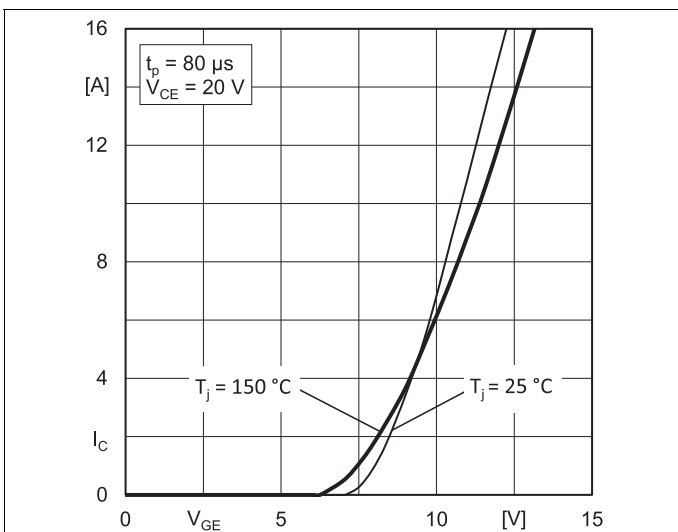


Fig. 5: Typ. transfer characteristic

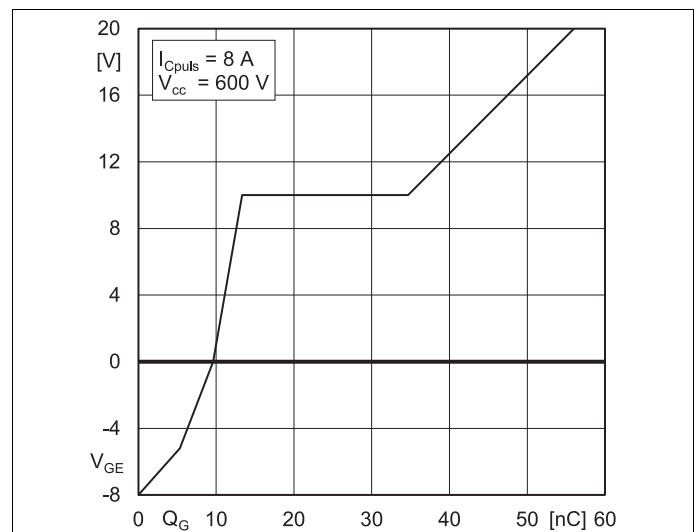


Fig. 6: Typ. gate charge characteristic

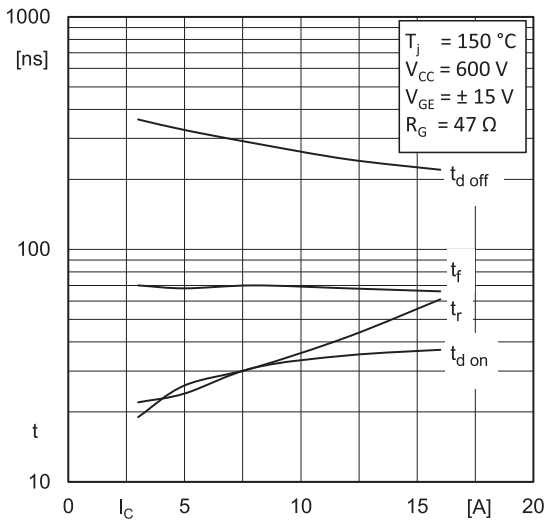


Fig. 7: Typ. switching times vs. I_C

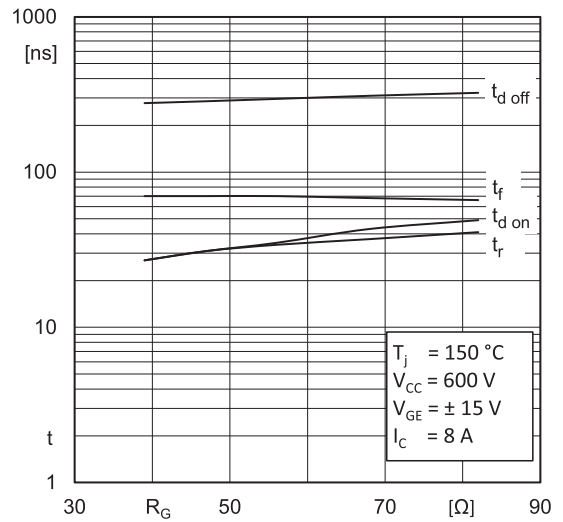


Fig. 8: Typ. switching times vs. gate resistor R_G

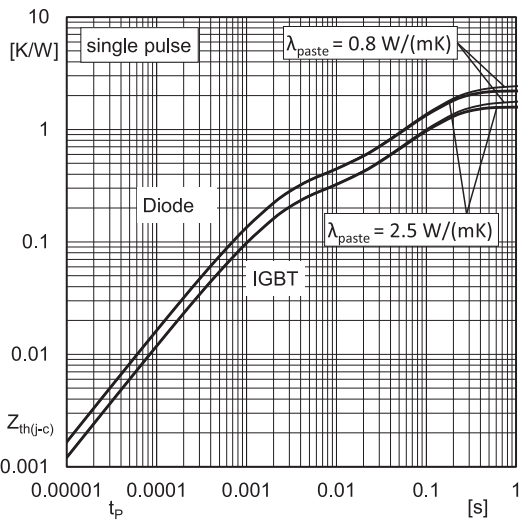


Fig. 9: Transient thermal impedance of IGBT and Diode

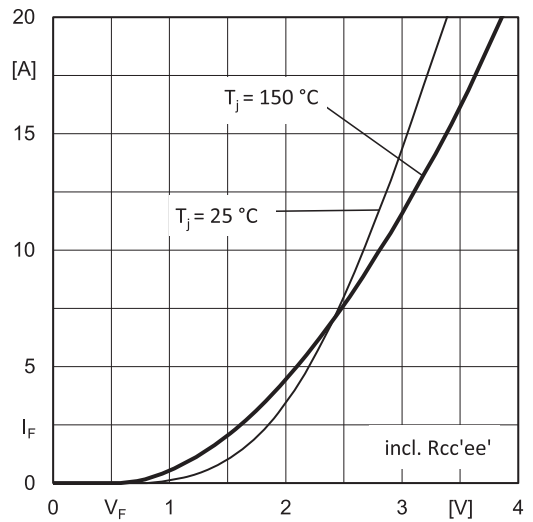


Fig. 10: CAL diode forward characteristic

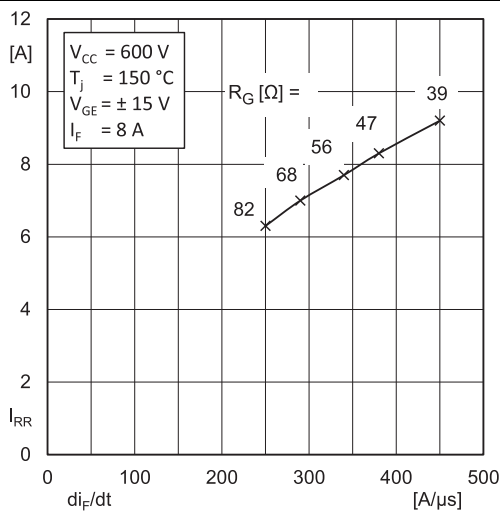


Fig. 11: Typ. CAL diode peak reverse recovery current

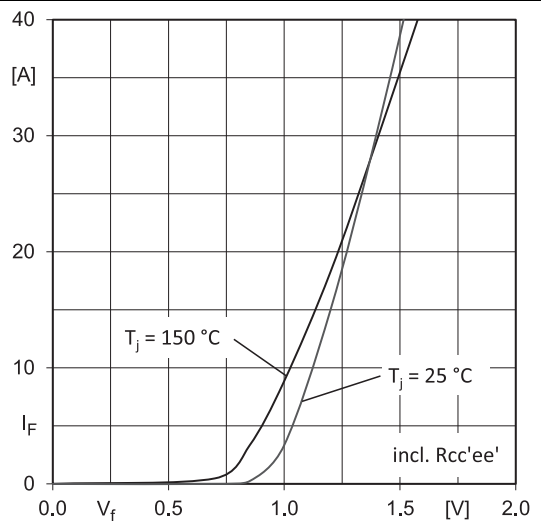
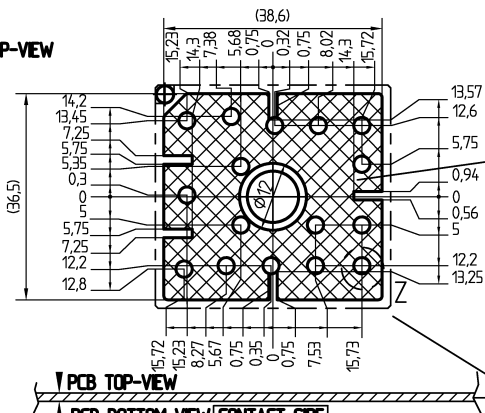


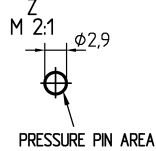
Fig. 12: Typ. input bridge forward characteristic

PCB PCB TOP-VIEW



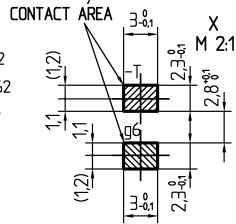
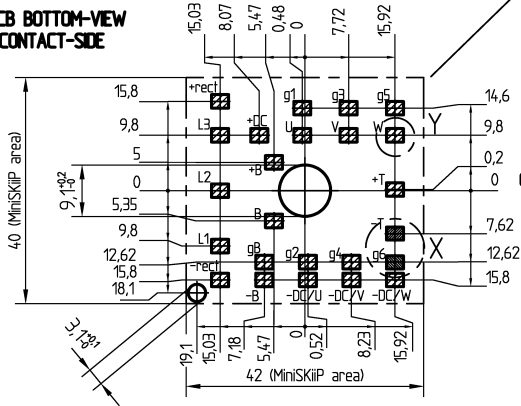
Only for the standard pressure part:
Accessible for mounting of SMD (max height 3.5) on PCB by customer

mounting area

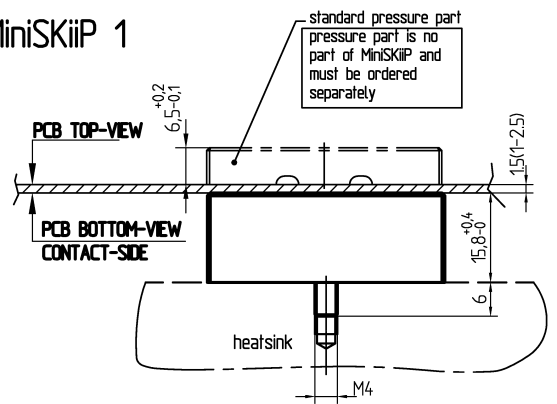


PCB TOP-VIEW
PCB BOTTOM-VIEW CONTACT-SIDE

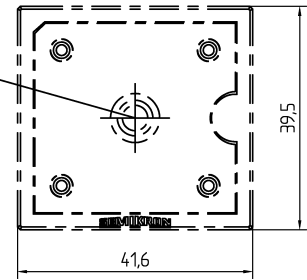
PCB BOTTOM-VIEW CONTACT-SIDE



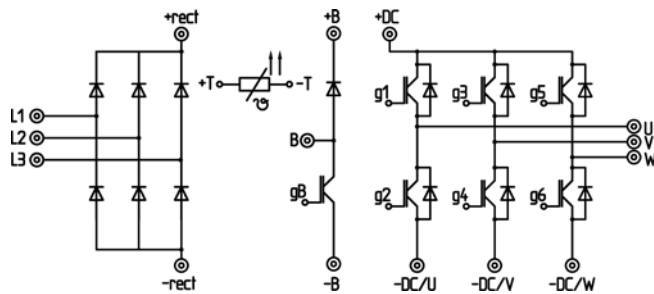
MiniSKiIP 1



For mounting please follow the assembly instruction



pinout, dimensions



⊙ power connector
• control connector

pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

***IMPORTANT INFORMATION AND WARNINGS**

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